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# 4V Drive Pch MOSFET

## TT8J2

### ●Structure

Silicon P-channel MOSFET

### ●Features

- 1) Low On-resistance.
- 2) High Power Package.
- 3) Low voltage drive. (4V)

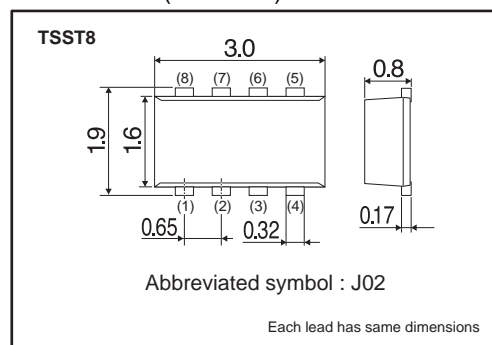
### ●Applications

Switching

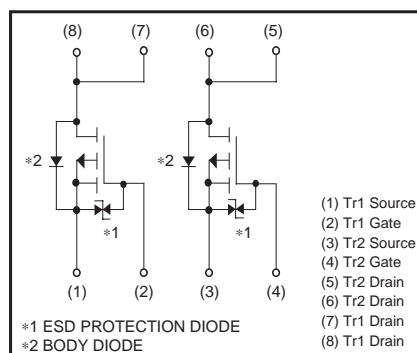
### ●Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
TT8J2		○

### ●Dimensions (Unit : mm)



### ●Inner circuit



### ●Absolute maximum ratings (Ta=25°C)

<It is the same ratings for the Tr1 and Tr2.>

Parameter	Symbol	Limits	Unit
Drain-source voltage	$V_{DSS}$	-30	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	V
Drain current	Continuous	$I_D$	$\pm 2.5$ A
	Pulsed	$I_{DP}$ *1	$\pm 10$ A
Source current (Body diode)	Continuous	$I_S$	-0.8 A
	Pulsed	$I_{SP}$ *1	-10 A
Total power dissipation	$P_D$ *2	1.25	W / TOTAL
		1.0	W / ELEMENT
Channel temperature	$T_{ch}$	150	°C
Range of Storage temperature	$T_{stg}$	-55 to +150	°C

\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$

\*2 When mounted on a ceramic board

### ●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ *	100	°C / W / TOTAL
		125	°C / W / ELEMENT

\* Mounted on a ceramic board

**TT8J2**
**Data Sheet**
**●Electrical characteristics (Ta=25°C)**

&lt;It is the same characteristics for the Tr1 and Tr2.&gt;

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	$\pm 10$	$\mu A$	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	-30	-	-	V	$I_D=-1mA, V_{GS}=0V$
Zero gate voltage drain current	$I_{DSS}$	-	-	-1	$\mu A$	$V_{DS}=-30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	-1.0	-	-2.5	V	$V_{DS}=-10V, I_D=-1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	-	60	84	m $\Omega$	$I_D=-2.5A, V_{GS}=-10V$
		-	95	130	m $\Omega$	$I_D=-1.2A, V_{GS}=-4.5V$
		-	115	160	m $\Omega$	$I_D=-1.2A, V_{GS}=-4V$
Forward transfer admittance	$ Y_{fs} $ *	1.8	-	-	S	$V_{DS}=-10V, I_D=-2.5A$
Input capacitance	$C_{iss}$	-	460	-	pF	$V_{DS}=-10V$
Output capacitance	$C_{oss}$	-	65	-	pF	$V_{GS}=0V$
Reverse transfer capacitance	$C_{rss}$	-	40	-	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}$ *	-	7	-	ns	$V_{DD}\cong -15V$ $V_{GS}=-10V$
Rise time	$t_r$ *	-	20	-	ns	$I_D=-1.2A$
Turn-off delay time	$t_{d(off)}$ *	-	35	-	ns	$R_L\cong 12.5\Omega$
Fall time	$t_f$ *	-	14	-	ns	$R_G=10\Omega$
Total gate charge	$Q_g$ *	-	4.8	-	nC	$V_{DD}\cong -15V$ $V_{GS}=-5V$
Gate-source charge	$Q_{gs}$ *	-	1.8	-	nC	$I_D=-2.5A$
Gate-drain charge	$Q_{gd}$ *	-	1.2	-	nC	$R_L\cong 6\Omega / R_G=10\Omega$

\*Pulsed

**●Body diode characteristics (Source-drain) (Ta=25°C)**

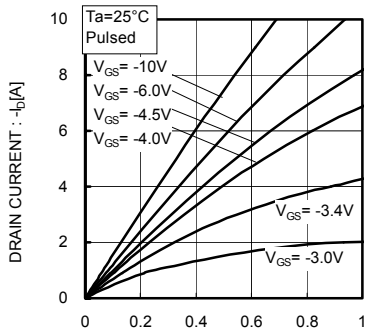
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	$V_{SD}$ *	-	-	-1.2	V	$I_S=-2.5A, V_{GS}=0V$

\* Pulsed

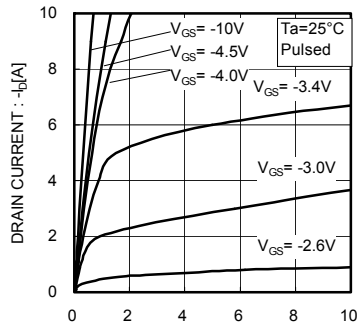
**TT8J2**

**Data Sheet**

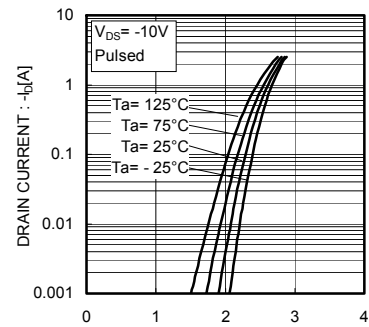
● **Electrical characteristic curves**



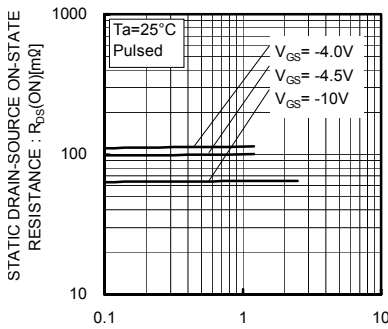
DRAIN-SOURCE VOLTAGE : -V<sub>DS</sub>[V]  
 Fig.1 Typical Output Characteristics ( I )



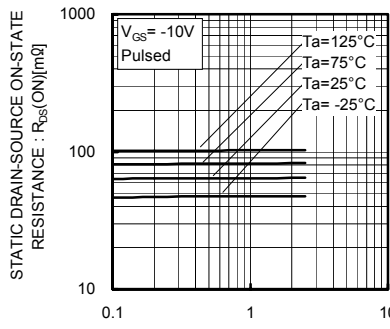
DRAIN-SOURCE VOLTAGE : -V<sub>DS</sub>[V]  
 Fig.2 Typical Output Characteristics( II )



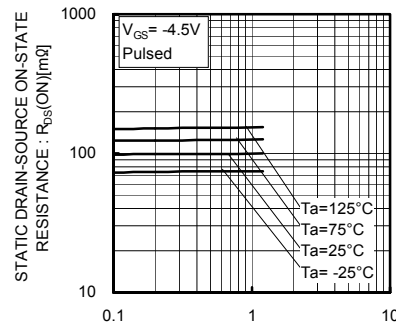
GATE-SOURCE VOLTAGE : -V<sub>GS</sub>[V]  
 Fig.3 Typical Transfer Characteristics



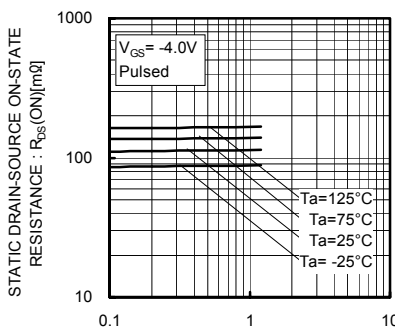
DRAIN-CURRENT : -I<sub>D</sub>[A]  
 Fig.4 Static Drain-Source On-State Resistance vs. Drain Current( I )



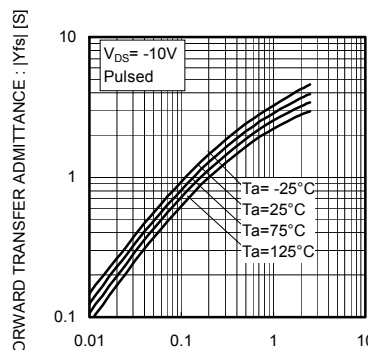
DRAIN-CURRENT : -I<sub>D</sub>[A]  
 Fig.5 Static Drain-Source On-State Resistance vs. Drain Current( II )



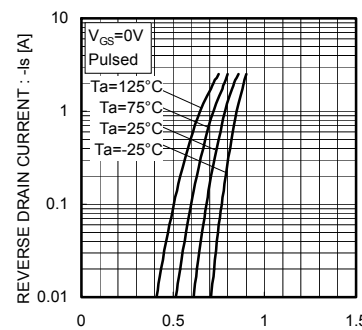
DRAIN-CURRENT : -I<sub>D</sub>[A]  
 Fig.6 Static Drain-Source On-State Resistance vs. Drain Current( III )



DRAIN-CURRENT : -I<sub>D</sub>[A]  
 Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)



DRAIN-CURRENT : -I<sub>D</sub>[A]  
 Fig.8 Forward Transfer Admittance vs. Drain Current



SOURCE-DRAIN VOLTAGE : -V<sub>SD</sub> [V]  
 Fig.9 Reverse Drain Current vs. Source-Drain Voltage

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**Data Sheet**

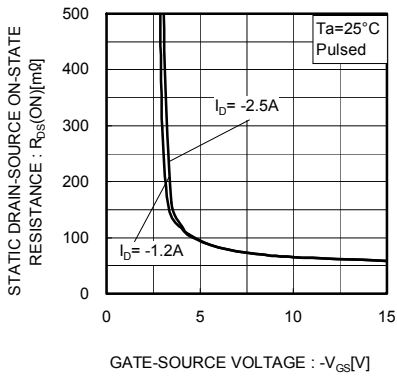


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage

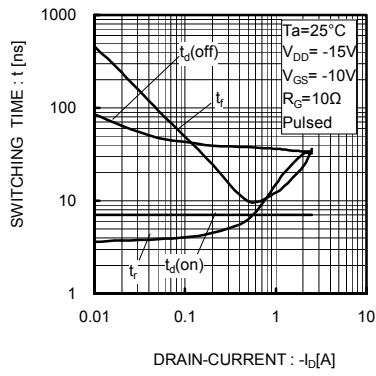


Fig.11 Switching Characteristics

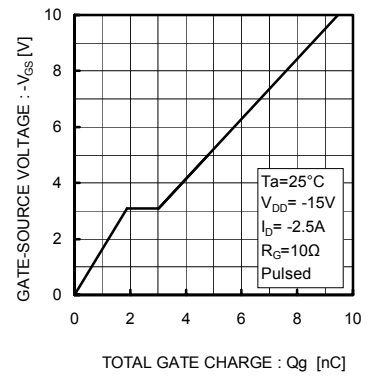


Fig.12 Dynamic Input Characteristics

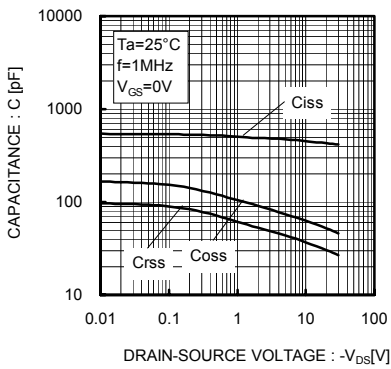


Fig.13 Typical Capacitance vs. Drain-Source Voltage

**TT8J2**

**Data Sheet**

● **Measurement circuits**

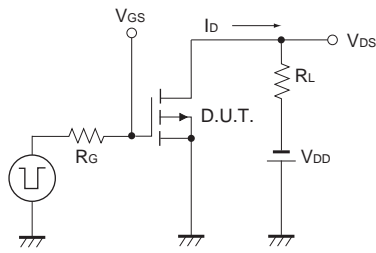


Fig.1-1 Switching Time Measurement Circuit

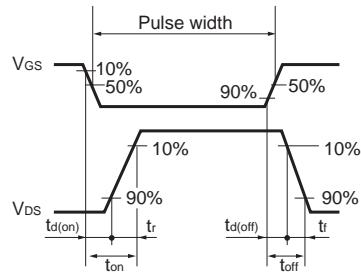


Fig.1-2 Switching Waveforms

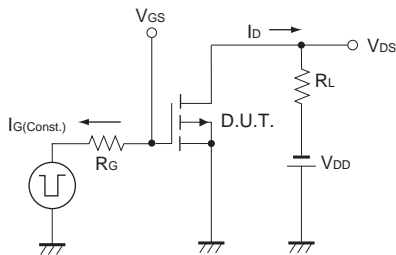


Fig.2-1 Gate Charge Measurement Circuit

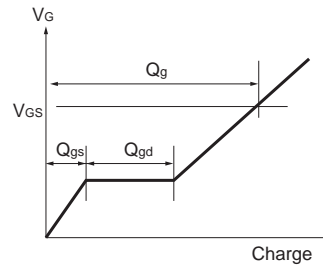


Fig.2-2 Gate Charge Waveform

● **Notice**

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

## Appendix

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